

### ■ Pin Description

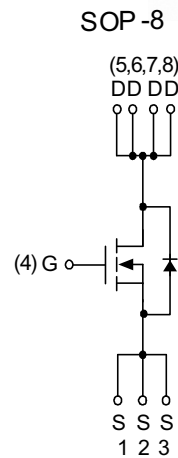
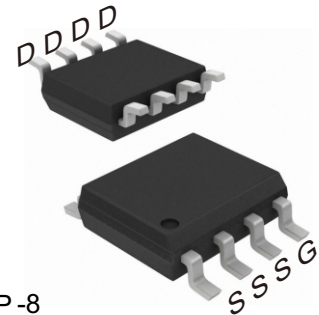
#### ■ Features

- 60V/12A  
 $R_{DS(ON)} = 12m\Omega$  (max.) @  $V_{GS} = 10V$   
 $R_{DS(ON)} = 14.5m\Omega$  (max.) @  $V_{GS} = 4.5V$
- Reliable and Rugged.
- Lead free and green device available (RoHS compliant).

#### ■ Application

- Secondary side synchronous rectification.
- DC-DC converter.
- Motor control.
- Load Switching.

#### ■ Absolute Maximum Ratings ( $T_A = 25^\circ C$ unless otherwise specified)

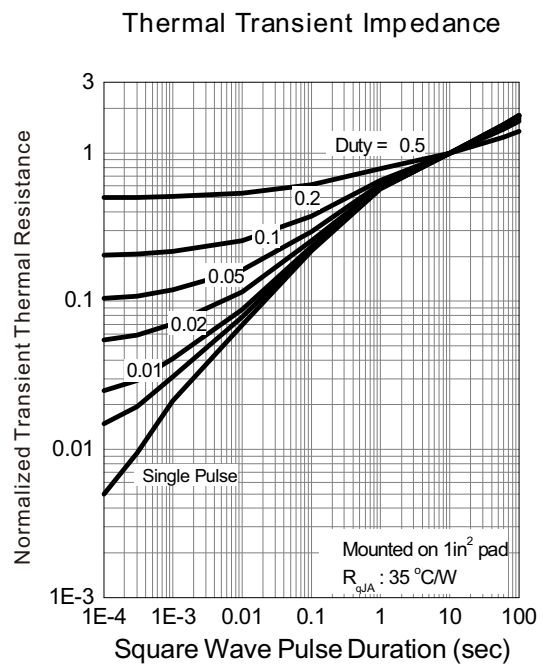
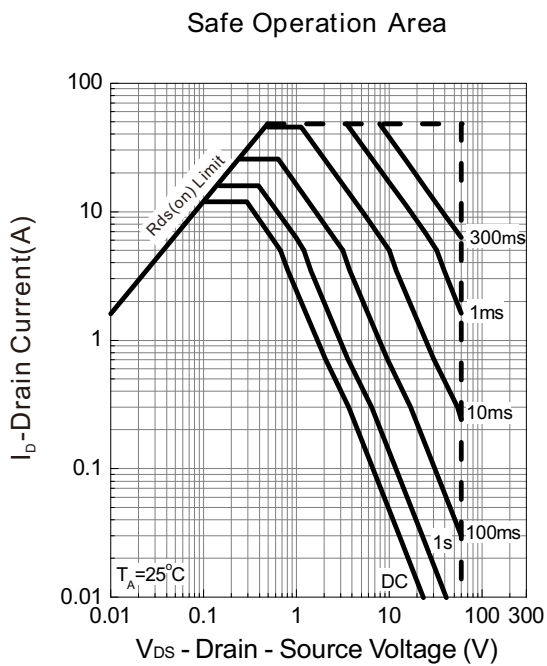
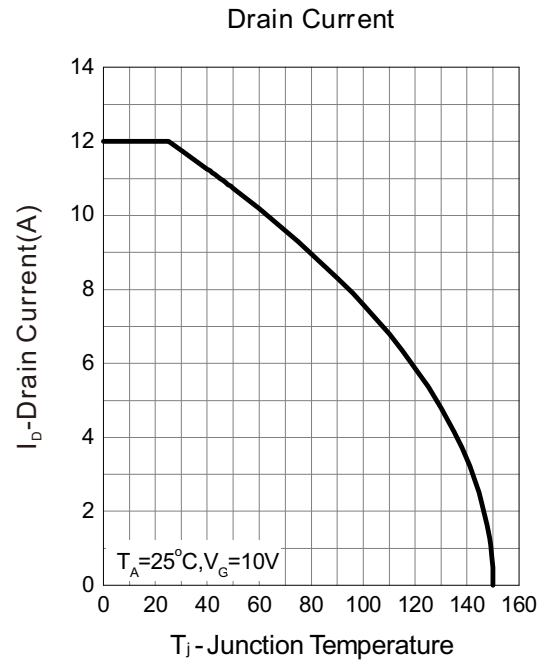
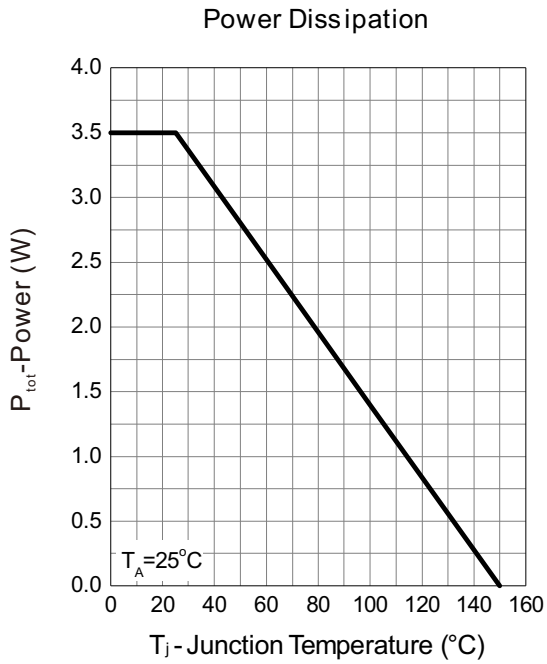


PARAMETER	CONDITIONS	Symbol	MSL120N06G	UNIT
Drain-Source Voltage		$V_{DSS}$	60	V
Continuous Drain Current	$T_A = 25^\circ C$	$I_D$	12	A
	$T_A = 70^\circ C$		9.5	
Pulsed Drain Current (note:1)	$T_A = 25^\circ C$	$I_{DM}$	48	
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Diode Continuous Forward Current	$T_A = 25^\circ C$	$I_S$	6	A
Avalanche Current, single pulse (note:2)	$L=0.5mH$	$I_{AS}$	20	A
Avalanche Energy, single pulse (note:2)	$L=0.5mH$	$E_{AS}$	100	mJ
Maximum Power Dissipation	$T_A = 25^\circ C$	$P_D$	3,5	W
	$T_A = 100^\circ C$		2,2	
Thermal Resistance-Junction to Ambient(note:3)	$t \leq 10s$	$R_{\theta JA}$	35	$^\circ C/W$
	Steady State		70	
Operating and Storage Temperature Range		$T_J, T_{STG}$	-55 ~ +150	$^\circ C$

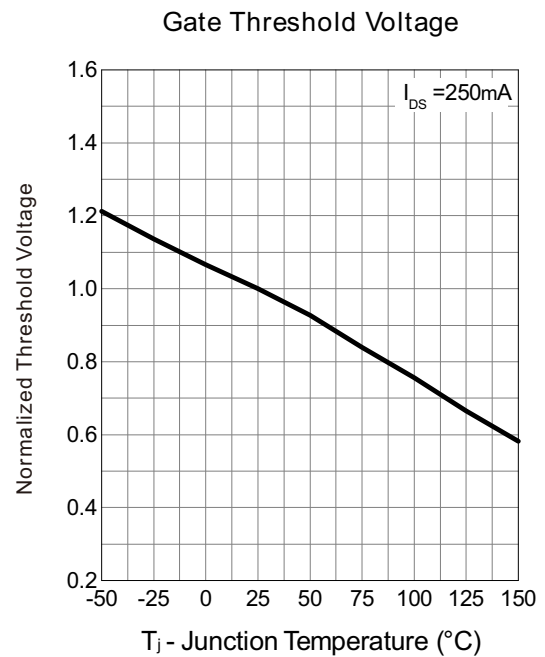
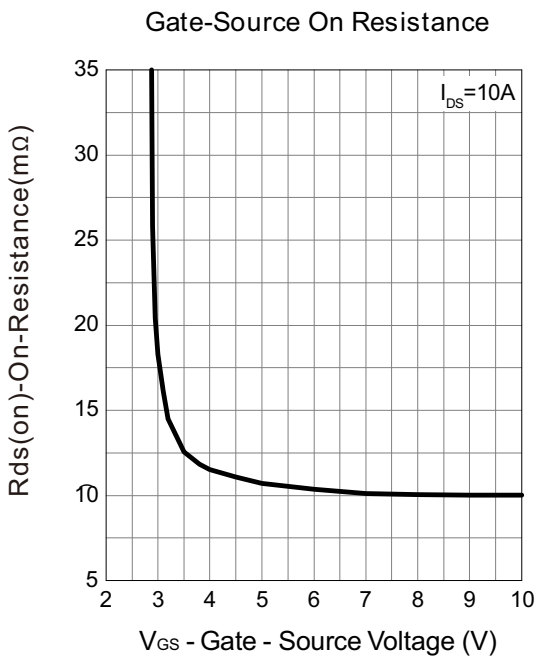
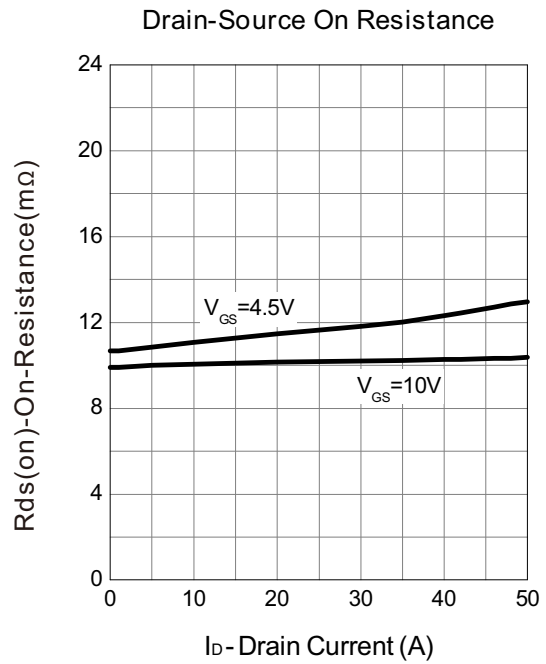
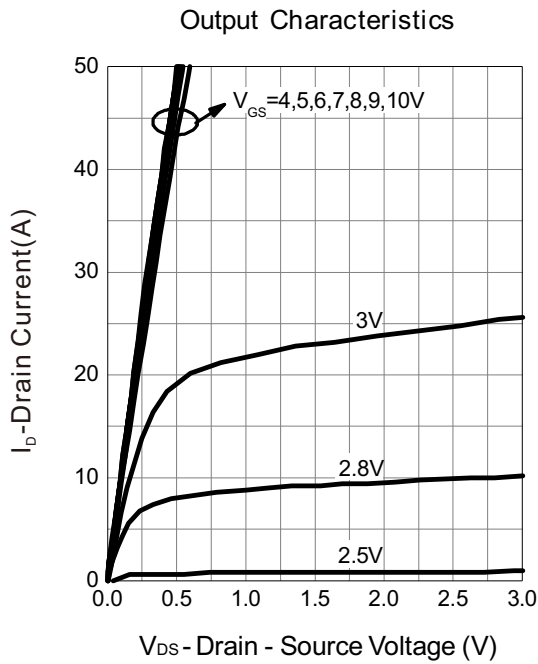
NOTE : 1.Repetitive rating; pulse width limited by maximum junction temperature.  
 2.UIS tested and pulse width limited by maximum junction temperature  $150^\circ C$  (initial temperature  $T_J = 25^\circ C$ ).  
 3.surface mounted on 1 inch per square pad area.

■ Electrical characteristics( $T_A = 25^\circ\text{C}$ unless otherwise specified)						
PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{DS} = 250\mu\text{A}$	$V_{DSS}$	60			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\mu\text{A}$	$V_{GS(th)}$	1	2	3	V
Zero Gate Voltage Drain Current	$V_{DS} = 48V, V_{GS} = 0V$	$I_{DSS}$			1	uA
	$V_{DS} = 48V, V_{GS} = 0V, T_j = 85^\circ\text{C}$				30	
Gate Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	$I_{GSS}$			$\pm 100$	nA
Drain-Source On-state Resistance(note:4)	$V_{GS} = 10V, I_{DS} = 10A$	$R_{DS(on)}$		10	12	m $\Omega$
	$V_{GS} = 4.5V, I_{DS} = 8A$			11	14.5	
■ Diode Characteristics						
PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Diode Forward Voltage(note:4)	$I_{SD} = 5A, V_{GS} = 0V$	$V_{SD}$		0.8	1.3	V
Reverse Recovery Time	$I_{SD} = 10A, dI_{SD}/dt = 100A/\mu\text{s}$	$t_{RR}$		28		ns
Reverse Recovery Charge		$Q_{RR}$		35		nC
■ Dynamic Characteristics(note:5)						
PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Gate Resistance	$V_{GS} = 0V, V_{DS} = 0V, F = 1.0\text{MHz}$	$R_G$		1		$\Omega$
Input Capacitance	$V_{DS} = 30V, V_{GS} = 0V, F = 1.0\text{MHz}$	$C_{iss}$		2500	3500	pF
Output Capacitance		$C_{oss}$		215		
Reverse Transfer Capacitance		$C_{rss}$		105		
Turn on Delay Time	$V_{DD} = 30V, R_L = 30\Omega, I_{DS} = 1A$ $V_{GEN} = 10V, R_G = 6\Omega$	$t_{d(on)}$		18	33	ns
Turn on Rise Time		$t_r$		10	18	
Turn off Delay Time		$t_{d(off)}$		73	131	
Turn off Fall Time		$t_f$		27	49	
■ Gate-Charge Characteristics(note:5)						
PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Total Gate Charge	$V_{DS} = 30V, V_{GS} = 4.5V, I_{DS} = 10A$	$Q_g$		22		nC
Total Gate Charge	$V_{DS} = 30V, V_{GS} = 10V, I_{DS} = 10A$	$Q_g$		45	65	
Gate-Source Charge		$Q_{gs}$		9		
Gate-Drain Charge		$Q_{gd}$		8.5		
NOTE : 4.Pulse test; pulse width $\leq 300\mu\text{s}$ , duty cycle $\leq 2\%$ . 5.Guaranteed by design, not subject to production testing.						

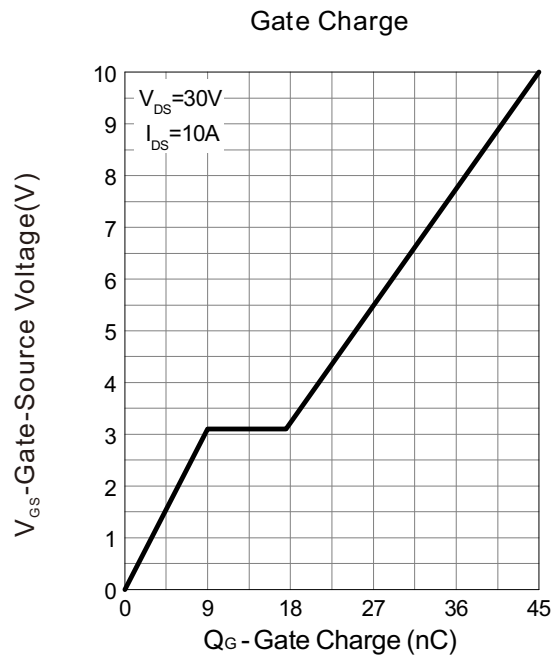
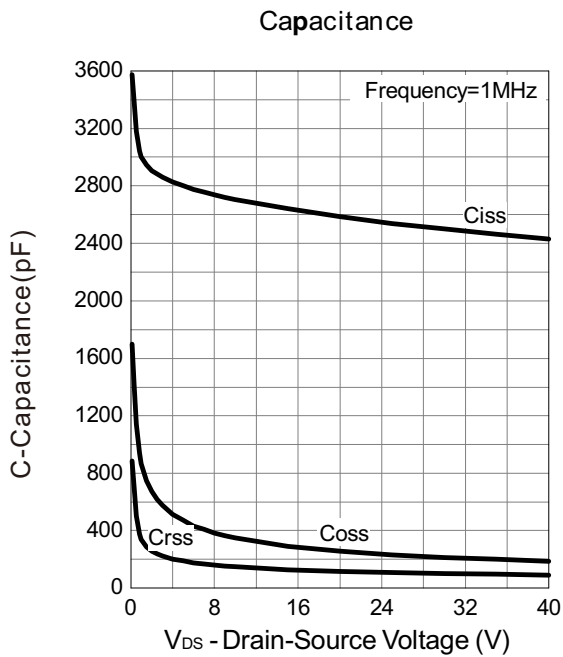
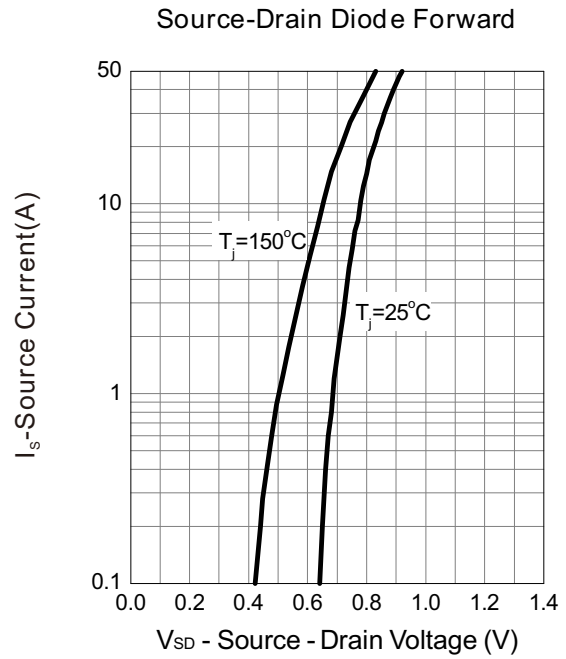
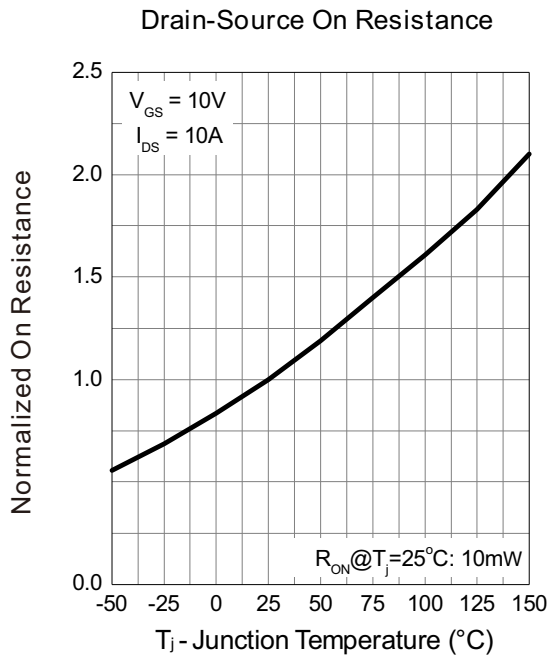
Rating and characteristic curves



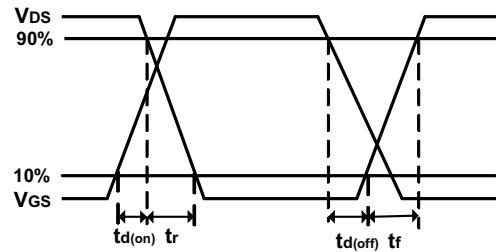
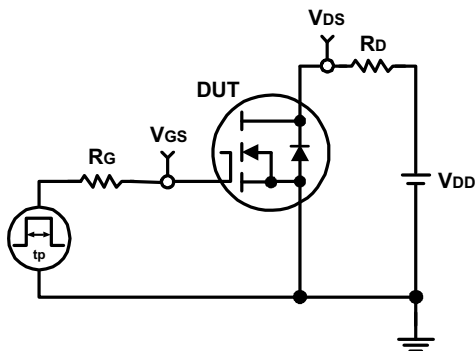
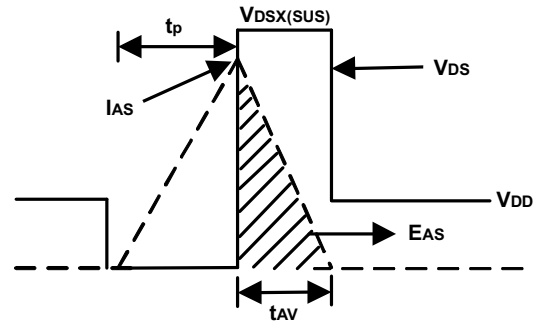
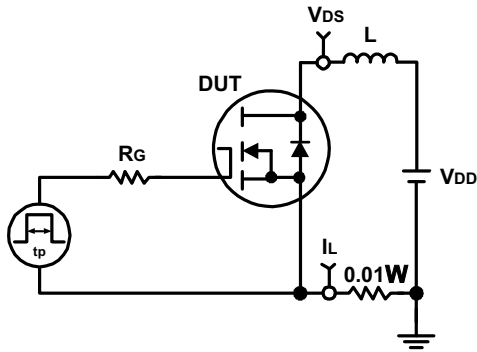
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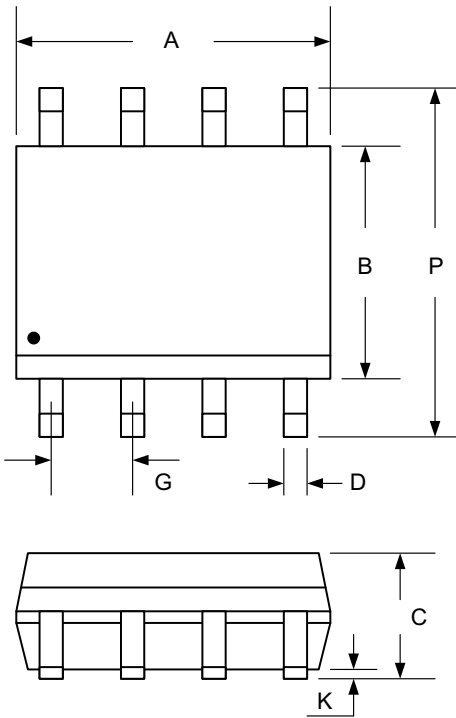


■ Test circuit and waveform



■ Package Information

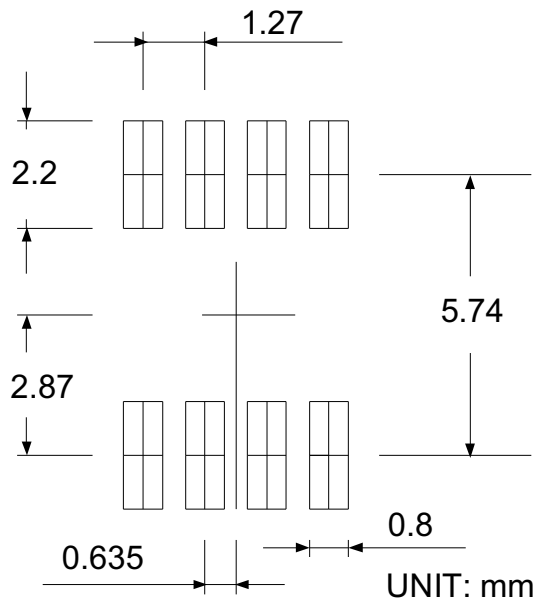
SOP-8 packag



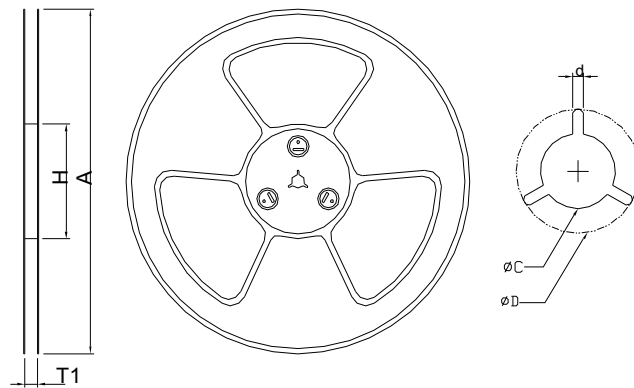
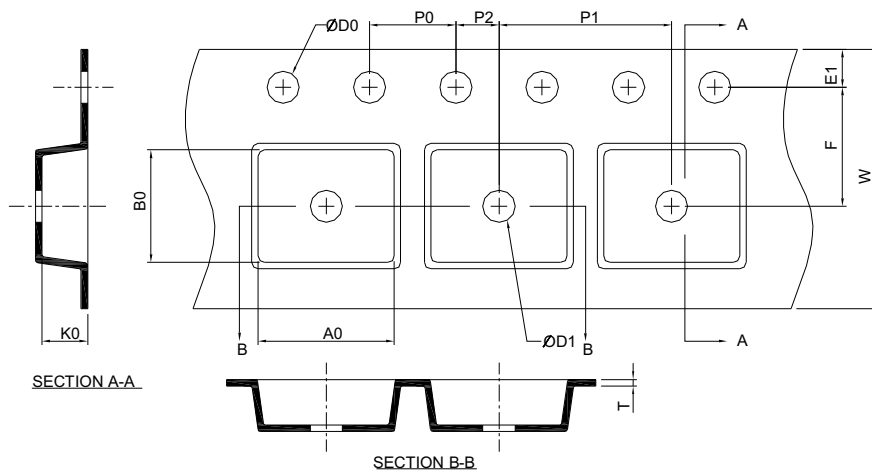
Symbol	Dimensions (mm)		Dimensions (inches)	
	Minimum	Maximum	Minimum	Maximum
A	4.800	5.000	0.189	0.196
B	3.800	4.000	0.150	0.157
C	1.350	1.750	0.054	0.068
D	0.310	0.510	0.012	0.020
F	0.400	1.270	0.016	0.050
G	1.27 BSC		0.05 BSC	
J	0.170	0.250	0.007	0.009
K	0.100	0.250	0.004	0.008
P	5.800	6.200	0.229	0.244
R	0.250	0.500	0.010	0.019

Package Dimensions (Controlling dimensions are in millimeters)

RECOMMENDED LAND PATTERN



■ Carrier Tape and Reel Dimension

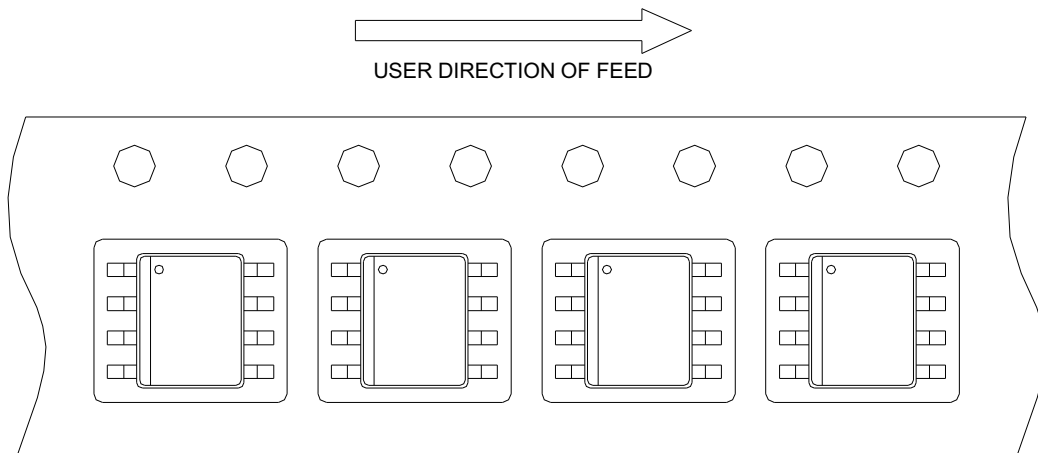


Application	A	H	T1	C	d	D	W	E1	F
SOP-8	330.0±2.00	50 MIN.	12.4+2.00 -0.00	13.0+0.50 -0.20	1.5 MIN.	20.2 MIN.	12.0±0.30	1.75±0.10	5.5±0.05
	P0	P1	P2	D0	D1	T	A0	B0	K0
	4.0±0.10	8.0±0.10	2.0±0.05	1.5+0.10 -0.00	1.5 MIN.	0.6+0.00 -0.40	6.40±0.20	5.20±0.20	2.10±0.20

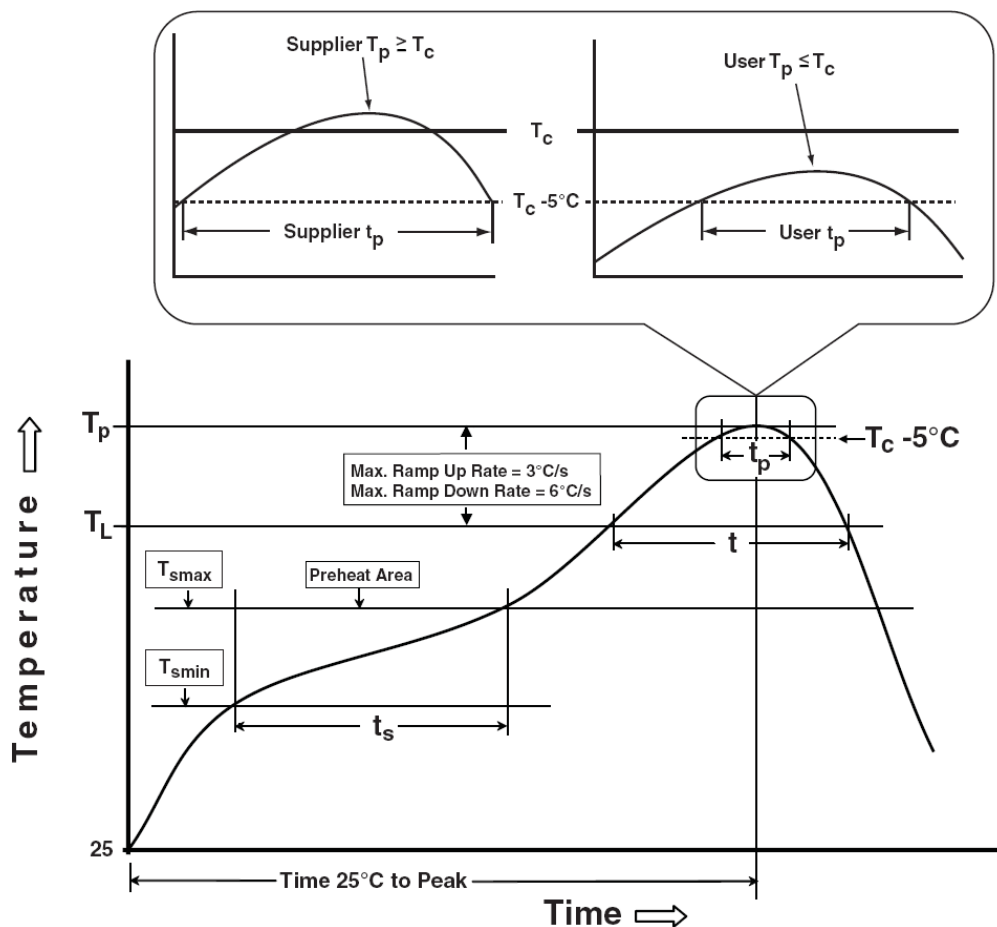
(mm)



■ Tapping Direction Information  
SOP-8



■ Classification Profile



### ■ Classification Reflow Profile

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
<b>Preheat &amp; Soak</b>		
Temperature min ( $T_{smin}$ )	100 °C	150 °C
Temperature max ( $T_{smax}$ )	150 °C	200 °C
Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )	60-120 seconds	60-120 seconds
Average ramp-up rate ( $T_{smax}$ to $T_p$ )	3 °C/second max.	3°C/second max.
Liquidous temperature ( $T_L$ )	183 °C	217 °C
Time at liquidous ( $t_L$ )	60-150 seconds	60-150 seconds
Peak package body Temperature ( $T_p$ )*	See Classification Temp in table 1	See Classification Temp in table 2
Time ( $t_p$ )** within 5°C of the specified classification temperature ( $T_c$ )	20** seconds	30** seconds
Average ramp-down rate ( $T_p$ to $T_{smax}$ )	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.
* Tolerance for peak profile Temperature ( $T_p$ ) is defined as a supplier minimum and a user maximum. ** Tolerance for time at peak profile temperature ( $t_p$ ) is defined as a supplier minimum and a user maximum.		

Table 1. SnPb Eutectic Process – Classification Temperatures ( $T_c$ )

Package Thickness	Volume mm <sup>3</sup> <350	Volume mm <sup>3</sup> ≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2. Pb-free Process – Classification Temperatures ( $T_c$ )

Package Thickness	Volume mm <sup>3</sup> <350	Volume mm <sup>3</sup> 350-2000	Volume mm <sup>3</sup> >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
≥2.5 mm	250 °C	245 °C	245 °C

### ■ Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HTRB	JESD-22, A108	1000 Hrs, 80% of VDS max @ $T_{jmax}$
HTGB	JESD-22, A108	1000 Hrs, 100% of VGS max @ $T_{jmax}$
PCT	JESD-22, A102	168 Hrs, 100%RH, 2atm, 121°C
TCT	JESD-22, A104	500 Cycles, -65°C~150°C

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